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Phase Transitions and Anion Exchange in All-Inorganic Halide Perovskites

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CONSPECTUS:

A new generation of semiconducting materials based on metal halide perovskites has recently been launched into the scientific spotlight, exhibiting outstanding optoelectronic properties and providing promise for the development of efficient optical devices. As a vivid example, solar cells made from these materials have quickly reached conversion efficiencies exceeding 25%, now on par with well-established technologies, like silicon. Their widespread success is due, in part, to a unique ability to retain high-quality optoelectronic performance while being easily solution-processed into thin films. This feature is what defines them as a brand-new class of optoelectronic materials, with the ability to compete with traditional semiconductors requiring higher processing costs, like the III-Vs or II-IVs. However, the interesting photophysics of metal halide perovskites come with a catch; their soft ionic lattice promotes complex thermal-induced phase transitions and a high capacity for post-synthetic compositional changes, e.g. halide anion exchange. Such dynamic behavior has ultimately made understanding several important structure-property relationships ambiguous and obstructed a clear path toward commercialization due to inherent phase instability.

Our aim in this Account is to highlight the fundamental aspects of metal halide perovskites that dictate a stable crystal structure and enable efficient anion exchange, through the lens of thermodynamic preference and phase formation energies. Taking the all-inorganic CsPbI_{3-x}Br_x system as a suitable case study, we focus on several ways in which its thermodynamically unstable perovskite structure can be maintained at room temperature and elucidate the restructuring pathways taken during destabilization. In addition, we will discuss the origin and mechanisms of post-synthetic anion exchange in CsPbX₃ (X=I, Br, Cl) perovskites, with emphasis made toward direct visualization using *in situ* optical micro-spectroscopy and arriving at quantitative results. For several notable features of halide perovskites dealt with in this Account – e.g. strain-stabilization, non-perovskite phase restructuring pathway and lattice anion diffusion – we attempt to rationalize them using state-of-the-art materials modelling techniques.

It is within this spirit that we not only modify a broad range of properties existing within metal halide perovskites, but regulate them, for enhanced material functionality. For example, controlling partial phase changes and local replacement of halide composition in CsBX₃ (B=Pb, Sn and X=I, Br, Cl) nanowires can facilitate the formation of optoelectronic heterojunctions, due to the abrupt change

in local crystal structure and the correlated transition in optoelectronic properties. From this combined perspective, metal halide perovskites appear as highly dynamic systems, whereby structural and compositional modifications have large a impact on the underlying phase stability and optoelectronic properties. Thus, we highlight several scientific aspects important to the fundamental understanding of metal halide perovskites, ranging from the underlying mechanism and kinetics through which phase destabilization and anion exchange take place, to tuning the thermodynamic energy landscape using external stimuli. We anticipate that providing a clear perspective for these topics will help deepen our knowledge of the nature of ionic semiconductors and provide the stimulus required to build new research directions toward utilizing halide perovskites within versatile optoelectronic devices.



1. INTRODUCTION

Following key discoveries in 2009¹ and 2012^{2,3}, the revival of organic-inorganic metal halide perovskite semiconductors has launched a new era of low-cost and high-performance photonics research⁴. Their rise to prominence has been greatly influenced by their unique ability to combine facile solution processing methods with high-quality optoelectronic properties⁵; from tunable, efficient light absorption and emission at visible wavelengths, to long carrier lifetimes and diffusion lengths. Consequently, metal halide perovskites have found potential within a broad range of optoelectronic applications, most notably cheap and efficient solar cells⁶. This rapid progress has capitalized on over 20 years of research into related dye-sensitized and organic solar cells, and goes far beyond what was previously expected for devices based on solution-processed thin films⁷. While the desirable optoelectronic properties of halide perovskites have both driven and guided interesting research, their poor stability under typical operating conditions has played the role of its Achilles heel. This sentiment was recently highlighted by Yang and You⁸, where they urge the field to ``*Make Perovskite Solar Cells Stable*".

In this Account, we will examine the topic of polymorphism and anion exchange (i.e. partial replacement of halide components) within halide perovskites research and develop a conceptual framework for understanding what triggers phase destabilisation at room temperature (RT). Focusing on all-inorganic halide perovskites, we summarize several different research lines we have taken to explore, understand, and regulate the phase energetics and material compositions, via anion exchange. A central theme of the research is a reliance on *in situ* characterisation and visualisation of phase transition phenomena, to correlate important (photo)physical aspects to the phase diagrams. For instance, *in situ* synchrotron-based X-ray diffraction has helped us elucidate the microstructural differences of strain-stabilized thin films, while *in situ* optical methods have helped reveal the underlying dynamics and mechanisms of anion exchange processes. Thus, precise control of perovskite phase and composition in nanocrystals, and the important optoelectronic properties, is shown possible. In terms of materials engineering for optoelectronic applications, we end the Account by highlighting the development of functional perovskite nanomaterials with highly tunable properties.

2. THE METAL HALIDE PEROVSKITE STRUCTURE AND STABILITY

Perovskites are materials that crystallize in the same structure as calcium titanate (CaTiO3), described by general formula ABX₃ (Figure 1A). Here, A is cation, B is a divalent metal (Pb, Sn, Ge), and X is a halide anion (I, Br, or Cl), with a lattice formed through a network of dynamic cornersharing octahedra, [BX₆]⁴⁻. For organic-inorganic lead halide perovskites, size restrictions within the ionic lattice necessitates the use of small A-site organic cations, e.g., methylammonium (MA: CH₃NH₃⁺) or formamidinium (FA: H₂NCHNH₂⁺). A central problem in the use of hygroscopic and volatile organic cations is their tendency to promote degradation pathways^{9–11}, representing a major obstacle toward long-term stability. Alternatively, switching to all-inorganic caesium lead halide (CsPbX₃) perovskites allows for the coupling of high optoelectronic performance (e.g. solar cell photoconversion efficiencies above 18%¹²) with a huge improvement to the environmental stability^{13–15}. The high-temperature (HT) black phase of CsPbI₃-based perovskites¹⁶ has garnered the most attention due to its relatively narrow bandgap (1.73 eV) and sensitive response to the solar spectrum.



Figure 1. Phase transitions, anion exchange and the phase-energy landscape in polymorphic ABX₃ perovskites. (A) The archetypal cubic crystal structure (t = 1) and anion exchange concept for ABX₃ perovskites. When *t* deviates from unity, octahedral tilts are introduced to accommodate a pseudocubic distorted perovskite structure. (B) Illustration of reversible phase transitions in polymorphic perovskites, transitioning though pseudocubic structures *via* octahedral tilting and into a nonperovskite structure *via* bond breaking. (C) Overview of reported group-subgroup symmetries of tilted halide perovskites MAPbX₃ (X = I¹⁷, Br¹⁸, and Cl¹⁹), FAPbX₃ (X = I²⁰, Br²¹, and Cl²²), CsPbX₃ (X = I²³, Br²⁴, and Cl²⁵), and CsSnX₃ (X = I²⁶, Br²⁷ and Cl²⁸), with comparison to the archetypal CaTiO₃ perovskite system²⁹. The tilts are identified using Glazer's³⁰ notation and the dashed lines correspond to first-order transitions. Other subgroups have been reported under atypical environments and are not included for simplicity. Reproduced from reference 42 with permission from the International Union of Crystallography. (D) Overview of the thermal phase relations of pure CsPbI₃

and the different paths which can be taken, depending on sample preparation and heating/cooling ramps. Reproduced with permission from reference 38. Copyright 2019 American Association for the Advancement of Science (AAAS). (E) Illustrative energy diagrams of bulk CsPbI₃ (thick black lines) with comparisons to common modifications of the energy scheme.

2.1 Polymorphism

Perovskites universally exhibit rich structural diversity, a property derived from the potential for the dynamic octahedra to tilt within its corner-sharing network (Figure 1A). The ABX₃ perovskite structure is geometrically determined by the ionic radii of its constituent elements (i.e. R_A , R_B , and R_X); the ionic radii of common constituents are $A=Cs^+(1.88 \text{ Å})^{31}$, $MA^+(2.17 \text{ Å})^{32}$ and $FA^+(2.53 \text{ Å})^{32}$; $B=Pb^{2+}(1.19 \text{ Å})^{31}$ and $Sn^{2+}(1.18 \text{ Å})^{33}$; $X=Cl^-(1.81 \text{ Å})^{31}$, $Br^-(1.96 \text{ Å})^{31}$ and $\Gamma(2.20 \text{ Å})^{31}$. For a given temperature, T, the relative bonding lengths can be used to calculate the Goldschmidt's tolerance factor (in the traditional formalism³⁴).

$$t = \frac{R_A + R_X}{\sqrt{2}(R_B + R_X)} \,. \tag{1}$$

The concept of the Goldschmidt's tolerance factor³⁵ (Figure 1A) is nearly a century old and has been widely used to gauge the phase stability, whereby a perovskite crystal is expected to form in the approximate range $0.8 < t < 1.1^{36}$. Thermal expansion will impose a continuous change in the unit cell volume by varying the internal bond lengths at different rates. For any given composition, this thermal response leads to the limited temperature ranges for which a stable perovskite phase may form. For instance, the characteristic low-temperature (LT: non-perovskite, yellow in color) to hightemperature (HT: perovskite, black in color) phase transition temperatures of FAPbI₃ and CsPbI₃ perovskites are well-above RT; > 125 °C for FAPbI₃³⁷ and > 315 °C CsPbI₃³⁸. In contrast, due to its suitable molecular size, MAPbI₃ is generally stable at RT³⁹. The relatively high transition temperatures of FAPbI₃ and CsPbI₃ is what makes the phase stabilisation of the optoelectronically active black an important ongoing challenge within the field. Alternatively, B-site alloying⁴⁰ with smaller cations (e.g. Mn²⁺ or Sn²⁺) can also help to bring the tolerance factor closer to unity and bring about a RT stable perovskite crystal.

2.2 Octahedral tilting

Octahedral tilting is the source of both structural variation and destabilisation of the perovskite phase. Figure 1B illustrates how octahedral tilting prevents a corner-sharing network from collapsing while the temperature-dependent⁴¹ tolerance factor is shifted further away from unity, until bond bending is sufficient to break them and reform a non-perovskite (i.e. either side- or face-sharing octahedra). The restructuring of a parent cubic system into its lower symmetry sub-groups, and ultimately into a non-perovskite, is a fundamental feature in halide perovskites. Relative to an undistorted cubic perovskite (Pm-3m), Figure 1C overviews the 15 different space groups of tilted perovskite structures predicted using group theory by Howard and Stokes⁴². Glazer's notation³⁰ classifies octahedral distortions which translate through the crystal⁴³ during thermal expansion. Tilt identification can be understood using the general case depicted in Figure 1B, where subsequent layers being stacked along the tilt axis are tilted in-phase (+) and then antiphase (-), corresponding to the first and second cooling-induced tilts. Certain phase transition sequences are paralleled across different metal halide compositions within Figure 1C, highlighting the inherent tendency for perovskites to exhibit analogous phase behaviour. For instance, like the prototypical CaTiO₃ perovskite, technologically important strontium zirconate (SrZrO₃) also exhibit the phase sequence upon heating $Pnma \rightarrow I4/mcm \rightarrow Pm-3m$, albeit at temperatures well above 1000 °C⁴⁴.

2.3 Anion exchange

The flexible lattice and abundant halide vacancies in all-inorganic CsBX₃ perovskites enable facile switching of the halide sites post synthesis (Figure 1A). Anion exchange is achieved by supplying the original ABX₃ composition (i.e. CsPbBr₃) with an abundant source of the precursor of another anion species (i.e. I-, Cl-) in solution or vapor phase, at elevated or room temperature. The large halide concentration gradient between the exterior and interior of the original structure drives the diffusion of guest ions into the parent lattice, to realize partial or even complete replacement of the original anions. As the crystal structures and bandgaps are dominantly dependent on the anion composition in lead halide perovskites, anion exchange thus provides a rich dimension for structural, physical, and optical diversity. For instance, alloying a portion of the iodine with relatively smaller bromine atoms in CsPbI₃ has been shown effective at increasing *t* closer to 1 at RT, stabilizing the black phase¹⁵. Anion exchange can also shift the photoluminescence (PL) emission across the entire visible light

spectrum⁴⁵, thus offering an effective post-synthetic transformation strategy for generating complex semiconductor heterostructures that are not accessible by direct synthesis methods. With anion exchange being demonstrated versatile for modifying the structures and properties in halide perovskite crystals, our research has sought to gain deep insights into the exchange mechanisms taking place.

2.4 Thermal phase relations of all-inorganic CsPbI3: a perfectly unstable case study

The relatively small size of Cs⁺ imposes a low *t* value (~0.85) for CsPbI₃ at RT, making the formation of stable perovskite materials and devices challenging. Figure 1D illustrates the thermal phase relations of the different CsPbI₃, portraying its HT-CsPbI₃ black phases (so-called due to their comparable physical properties); cubic (α), tetragonal (β) and orthorhombic (γ). Upon cooling, the α -phase can pass through a variety of different restructuring paths, depending on conditions, The thermodynamically preferred cooling path (path 2)²³, though can remain in a HT-phase at RT (paths 3 and 4) if the driving force to transform into the low-temperature (LT) CsPbI3 phase is inhibited (path 5). The unstable phase energetics of bulk RT HT-CsPbI₃ is illustrated in Figure 1E. For instance, reheating kinetically trapped RT black CsPbI₃ crystal (accessible through thermal quenching) to a temperatures of 60 - 100 °C is sufficient to destabilize it⁴⁶⁻⁴⁸ (path 6). A central theme within our work has been to understand the transition mechanisms within the phase diagram outlined in Figure 1D and find ways to beneficially regulate it.

3. EXTERNAL TRIGGERS AND THE MODIFIED ENERGY LANDSCAPE

It is instructive to consider what happens to the phase diagram of CsPbI₃ within the framework of its modified energy schemes (Figure 1E). To stabilize the black phase at RT, one can either shift the relative phase formation energies or increase the energy barrier, inhibiting the transition. Conversely, external triggers like structural defects and certain surface interactions which catalyse destabilisation should be avoided. Thus, beyond compositional changes, creating functional CsPbI₃ perovskites unavoidably means diverging from a bulk-like state.

By reducing the crystal dimensionality a RT-stable HT-CsPbI₃ perovskite structure can be created via two separate influences. First, Luther et al⁴⁹ demonstrated that an inverse dependence of the tolerance factor with size shifts *t* closer to unity. Second, nanocrystals will experience a significantly

modified surface energy contribution. Zhao et al.⁵⁰ explored the relationship between the CsPbI₃ crystallite size and the perovskite phase stability, highlighting a large disparity in the surface energy between the HT-phase (0.13 J/m^2) and LT-phase (2.57 J/m^2), whereby a reversal in the relative Gibbs free energies is expected for crystals smaller than roughly a 100 nm-cubic.

Surface functionalization⁵¹ (often involving organic ligands) is another widely adopted stabilization strategy, which ionically binds the crystal surface and imposes tilting restrictions. Crystal surfaces in general are known to house the tail ends of structure-property distributions, including bonding angles, and often facilitate nucleation sites for phase transitions. Thus, restricting the surface tilts can increases the transition energy barrier, inhibiting normal phase transition kinetics (Figure 1E).

3.1 Straining to be black



Figure 2. Strain-induced stabilization of CsPbI₃-based perovskite thin films. (A) GIWAXS image (λ = 0.95774 Å) acquired from a quenched RT CsPbI₃ thin film, with expansions over selected diffraction peaks split in the in- and out-of-plane directions. (B) Schematic illustration of diffraction ring splitting in the GIWAXS signal, whereby a perovskite crystal forms a heterojunction with the substrate at high temperature and undergoes tensile strain and texture formation upon cooling. (C)

Optical images of a partially scrapped CsPbI₃ thin film surface (free NCs) recorded under N₂ at different temperatures during a quenching profile. (D) *Ab initio* energy diagram indicating the relative stability (at 0 K) of the HT-CsPbI₃ and LT-CsPbI₃ phases with and without in-plane biaxial strain. Note that the relative saddle point depth is undefined. (E) GIWAXS *t-T* profile of CsPbI_{2.7}Br_{0.3} thin film through a high-temperature LT-to-HT phase transition, followed by thermal cycling. Reproduced with permission from reference 38. Copyright 2019 American Association for the Advancement of Science (AAAS).

Introducing strain is an established path toward structural and compositional diversity in metastable semiconductors crystals⁵², because strain will inherently shift the system away from normal equilibrium conditions. For instance, when oxide perovskite thin films form heterojunctions with the underlying substrate and become clamped, the film must track any mechanical changes undertaken by the substrate, which can dramatically alter the free energy landscape of competing ferroelectric phases^{53,54}. Recently, Zhao et al.⁵⁵ demonstrated that high temperature annealing of organic-inorganic halide perovskite thin films formed strong interfaces with the substrate, regardless of the composition of the perovskite or substrate. Using synchrotron-based grazing incident wideangle X-ray scattering (GIWAXS) we examined the role that substrate clamping has on shifting the phase energetics in CsPbI₃ perovskite thin films. Resolving the 2D micro-structure (i.e. in- and outof-plane) of a thermally quenched HT-CsPbI₃ thin film in Figure 2A we found the crystal to be heavily strained by the substrate at RT. This occurs via two steps; (i) high temperature processing (330 °C) both transitions the CsPbI₃ film to the HT-phase and establishes a hetero-interface, as the soft perovskite crystal adapts to the substrate surface⁵⁵, and (ii) cooling biaxially strains the clamped thin film (Figure 2B), which has a much larger thermal expansion coefficient ($\alpha_T \sim 50 \times 10^{-6} \text{ K}^{-1}$) than the underlying substrate ($\alpha_T \sim 4$ to 9×10^{-6} K⁻¹).

Strain alters the energetics of the competing LT- and HT-phases^{16,53,56}, an effect vividly captured by us using *in situ* optical microscopy in Figure 1C; the material still clamped to the substrate becomes trapped in the HT-CsPbI₃ state at RT, whereas the detached materials readily turn to LT-CsPbI₃. The processes taking place during annealing underpin this observation of modified phase energetics (Figure 1D). First, the hetero-interface will increase the energy barrier height via restricted tilting, and cooling-induced strain will renormalize the phase formation energies (Figure 2D). To

elucidate the strain-induced shift in phase energetics, we calculated its response using DFT over 12 different planar strain directions. The averaged energy values are shown in Figure 2D confirming that the unstrained LT-phase is strongly favored over its HT-phase counterpart. Notably, however, biaxial strain imposes different energy penalties for the two phases and introduces a relative stabilization of the strained black perovskite structure. We further experimentally confirmed this response on other substrate surfaces and found that films grown with a thickness below a micron also exhibited similar strain profiles.

Evaluating the high temperature processing of a CsPbI_{2.7}Br_{0.3} thin film using in situ GIWAXS through multiple thermal cycles (Figure 2E), we found that the normally preferred LT-phase is replaced with a stable HT-phase after establishing a stained interface during the first heating ramp. Such thermodynamic behaviour is highlighted in Figure 1E and provides the kind of thermal stability desirable for NIR HT-CsPbI₃-based optoelectronic devices. Using this same thin film composition, we demonstrated a functioning LED device based on a strain-stabilized CsPbI_{2.7}Br_{0.3} active layer.

3.2 Moisture-induced shifts to the CsPbI₃ phase diagram



Figure 3. Moisture as a catalyst toward phase degradation. (A) Reversible work, $\Delta F(z)$, required to transfer an I⁻ atom from the solid perovskite to the thin adsorbed water layer, where direction z perpendicular to the interface. (B) MD simulation snapshot near the top of the energy barrier in (A), showing the lead halide sub-lattice (grey and orange), Cs⁺ cations (green), and water molecules (red and white). (C) Calculated iodide vacancy concentration, ρ_{ν} , per unit cell as a function of relative humidity, p/p_o . Reproduced with permission from reference 58. Copyright 2018 Springer Nature.

The ionic lattice of metal halide perovskites is water-soluble, leading to intrinsically poor stability under ambient operating conditions. When exposed to moisture or other polar molecules, the crystal surface can disassociate and degrade, stifling performance. Further, the metastable black HT-phase of CsPbI₃ has been widely reported to be sensitive to moisture⁴⁶. For example, our strained black CsPbI₃ thin films were shown to decay and turn yellow³⁸ within just several minutes of being exposed to an ambient atmosphere (27% RH).

We recently examined this problem in detail and tried to understand the underlying mechanisms of so-called moisture attack⁵⁷ and how it accelerates the HT- to LT-phase transition. Unlike the chemical decomposition in hybrid perovskite MAPbI₃, H₂O molecules only adsorb on CsPbI₃ surface and partially dissolve the halide anions. As a result, the increased halide vacancy concentration can lower the kinetic barrier and catalyse yellow phase formation, as outlined in Figure 3. Molecular dynamics (MD) simulations (Figure 3A and B) show an enhancement of halide vacancy formation at the water-perovskite interface due to the large solvation enthalpy of halide ions and low vacancy formation energy in the perovskite lattice. Consequently, the equilibrium halide vacancy concentration at the crystal surface is expected to rise as a function of increases relative humidity, as depicted in Figure 3C. Through increased adsorption of H₂O molecules, the equilibrium halide vacancy concentration can be enhanced up to five orders of magnitude compared to the bulk interior. Using ambient pressure X-ray photoemission spectroscopy (AP-XPS), we showed that water molecule catalysts are adsorbed only onto the surface without diffusing inside the crystal. Further, halide vacancies reduce the surface tension between the two phases and facilitate faster transition rates, a feature consistent with the experimental observations of faster transition times when the relative humidity is increased from 20% to 80%. Like water, we found other polar solvents such as methanol or ethanol can also trigger the phase transition, although their catalytic performances are not as efficient as water due to their weaker polarity.

3.3 Transitions between the LT and HT phases

The distinct difference in crystal structure between the perovskite and non-perovskite phases ultimately equates to fundamental differences in their photophysical properties, enabling the formation of phase-change optical devices. Such devices developed by us will be highlighted later. In order to understand the phase transition mechanisms and kinetics, we have used halide perovskite nanowires (NWs) as a model platform for investigating the rich solid–solid phase transition dynamics at a microscopic scale. We directly synthesized non-perovskite δ -CsPbI₃ NW structures via a low-temperature substrate-guided method utilizing its anisotropic internal crystal structure. Through heating (~320 °C) and a rapid thermal quench of the as-grown δ -CsPbI₃ NWs, they are transformed into a RT γ -phase. Additionally, the phase transition temperature can be reduced to ~150 °C via alloying of CsPbI₃ with Br, to form CsPbIBr₂. Once transformed into the perovskite phase, the NWs exhibited enhanced luminescence efficiency and a relatively narrow bandgap, enabling direct observation of the non-perovskite-to-perovskite phase transition dynamics using advanced nano-imaging techniques.



Figure 4. Phase transitions in soft lead halide perovskites are intermediated by a liquid-like physical state. (A) Histograms of phase propagation rate of CsPbBr₂I NWs heated to three different temperatures. The insets show characteristic NWs corresponding to different times of the phase conversion. (B) Arrhenius plot of experimental and MD simulation data; the solid red line is the linear

fit to the experimental data ($210 \pm 60 \text{ kJ/mol}$), and the solid blue line is the linear fit to the simulation data ($140 \pm 80 \text{ kJ/mol}$). The inset is a detailed plot of the experimental data. (C) Snapshots from the MD simulation of phase propagation as a function of time at 267 °C, showing the disordered interface between the LT and HT phases of CsPbBr₃. Here we have parameterized a classical forcefield for CsPbBr₃ crystals, which is used as a proxy for the structurally similar mixed halide perovskite studied experimentally. (D) Charge density profiles from the MD simulation at 267 °C, obtained by projecting ion positions onto the direction of the wire axis. Data are averaged over a 50 ns time window. Reproduced with permission from reference 59. Copyright 2020 Elsevier.

Nanoscale cathodoluminescence (CL) microscopy provides high spatial resolution and excellent sensitivity by exciting optically emissive materials with a scanning electron beam. Recently we applied CL *in situ* while heating and imaged the phase transition process from LT-CsPbIBr₂ to HT-CsPbIBr₂. Like LT-CsPbI₃ NWs, as-synthesized LT-CsPbIBr₂ NWs have a similar edge-sharing structure containing metal halide octahedral chains oriented along the major axis of the NW. As seen in Figure 4A, nucleation of the emissive HT-CsPbIBr₂ phase was typically observed at the NW ends, as indicated via bright CL emission and subsequent propagation along the wire. Through observing hundreds of CsPbIBr₂ NWs, we arrived at a statistical distribution for temperature-dependent (163 °C, 177 °C, and 182 °C) phase propagation rates (Figure 4A); the propagation rates are found to be 3.1 ± 0.2 nm/s, 11 ± 1 nm/s, and 33 ± 3 nm/s, respectively. In addition, we determined an activation energy of 210 ± 60 kJ/mol via Arrhenius fitting (Figure 4B), with the propagation rate as a function of temperature. A significant increase in entropy is expected to explain such a large energetic barrier, instead of the enthalpy change (~15 kJ/mol).

To understand the microscopic mechanism of phase propagation, we applied a classical force field to perform MD simulations in a simpler composition of CsPbBr₃. Figure 4C shows the MD simulations with (100) LT-CsPbBr₃ attaching to (100) HT-CsPbBr₃ at a phase interface, as determined by *ex-situ* selective area electron diffraction (SAED)⁵⁸. The simulations also suggest that the compensating increase in entropy promotes the formation of a structurally disordered amorphous interfacial layer, which helps to propagate the interphase boundary. The phenomena of phase propagation from our simulations agrees with the experimentally derived value of 140 ± 80 kJ/mol for the activation energy (Figure 4B). The growth of the HT-CsPbBr₃ structure is thus suggested propagates via ion diffusion across the amorphous phase interface (Figure 4C) instead of a

martensitic transformation. The mobile halide anions in the perovskite lattice are likely to guide the formation of HT-phases, as the halide species are distributed in a long-range order across the amorphous interface (Figure 4D).

3.4 Structure-property relationships in polymorphic crystals

Phase transitions involving a corner-sharing tilts present a much lower energy barrier compared to transitions requiring bond-breaking to form a non-perovskite structure²³. During phase transitions, certain properties will change, often discontinuously, in response to the change of external conditions, such as temperature or pressure. For example, we showed that phase transitions in CsPb_xSn_{1-x}I₃ NWs⁵⁹ are accompanied by both a dramatically altered optical bandgap and electrical conductivity. This is what brings complexity to understanding the dynamical nature of such transitions in devices operating near RT and connecting them to physical features which manifest at pre-phase transition boundaries. For a clear example, whether as-synthesized CsPbBr₃ quantum dots form a truly cubic structure at RT has been hotly debated.

The radiation-sensitive nature of halide perovskites has hindered structural studies at the atomic scale using high-energy electron beams. We have overcome this obstacle by applying low-dose high-resolution transmission electron microscopy to image the pristine atomic structure of ultrathin 2D CsPbBr₃ perovskites⁶⁰. Both orthorhombic and cubic perovskite phases of CsPbBr₃ are found to coexist in a single particle, probably owing to the small energy difference between their phase transitions. Thus, near the phase transition boundaries discontinuities in the optoelectronic properties will exist. Beyond abrupt changes in the PL peak position during the phase transitions in MAPbI₃, we have correlated electrical transport data to these phase transitions. Specifically, we performed longitudinal resistance (R_{xx}) measurements under steady-state illumination as a function of temperature, with the structural transitions tracked using linear thermal expansion⁶¹. We found that upon cooling down to cryogenic temperatures the electronic resistance decreased by a factor of two. However, precisely at the MAPbI₃ tetragonal-to-orthorhombic perovskite phase transition, R_{xx} sharply rises by over an order of magnitude before dropping again, to continue its decreasing trend while cooling in the orthorhombic regime. Such insights highlight how important it is to understand the (pre-)phase transition kinetics, which dramatically alter properties central to device performance.

In low dimensional crystals, like Ruddlesden-Popper (RP) phases consisting of two-dimensional perovskite slabs interleaved with cations, thermal-induced modifications to both phase and optoelectronic properties become interesting due to the interplay between the alternating layers. For instance, synthesizing single crystal $(BA)_2Cs_{n-1}Pb_nBr_{3n+1}$ with different layer numbers (n) we discovered⁶² that the tilted $[PbBr_6]^{4-}$ octahedra in the organic-inorganic RP phase perovskites align

along the [100] axis when the temperature increases from 100 K to 400 K. Further increasing in temperature induces a first-order phase transition from the orthorhombic to tetragonal space group, and the organic chains disorder. The structural dynamics correlate with a sudden drop in the PL intensity and consequently with LED device degradation, indicating heat management and phase control are essential to maintaining high performance devices.

Beyond structural phase transitions, distinct electronic transitions (i.e. semiconductor to metal transition, high T_c superconducting) are predicated theoretically in charge-ordered halide perovskites. To study such phenomena, we synthesized an In-based, charge-ordered (In^+/In^{3+}) inorganic halide perovskite $Cs_2In(I)In(III)Cl_6$ single crystals via a solid-state reaction method⁶³. Pressure-dependent optical absorbance spectroscopies further reveal the abrupt vanishing of the fundamental semiconductor bandgap, whereby increased absorption with a broadband metallic character is introduced. The experimental demonstration of pressure-induced semiconductor-to-metal phase transition was consistent with theoretical modeling, which may open a pathway toward the discovery and understanding of quantum phase transition in halide perovskites and inspire potential applications in quantum devices.

4. CONTROLLING PHASE AND ANION EXCHANGE AT THE NANOSCALE

Due to the high anion mobility and the rigidity of the cationic sublattice, anion exchange reactions preserve together the crystal structure, morphology and material quality of halide perovskites. As the halide composition directly governs the local optical properties, controlling the anion exchange reactions has proven useful in designing and forming semiconductor heterostructures which can be tracked readily by *in situ* PL microscopy. Such studies have yielded important kinetic information directly^{64,65} and, by developing different reaction procedures in solution and gas phases, we have quantitatively investigated the underlying physical mechanisms involved in the anion exchange process. In the end, precision of the anion exchange process has permitted us to realize novel optoelectronic heterojunctions.



Figure 5. Anion exchange kinetic processes and mechanism in all-inorganic CsPbX₃ perovskite crystals. (A) Schematic illustration of wide-field PL measurement of the thermal-driven anion interdiffusion on a CsPbCl₃–CsPbBr₃ heterojunction NW. (B) PL images and corresponded emission spectra for the heterojunction NW when heated constantly at 100 °C for different snapshots in time. Here the heterointerface moves towards the Br-rich region while the PL spectrum changes accordingly, with the merging of two peaks into one. Scale bar: 2 μ m. (C) Schematic illustration of the anion exchange sequence: (i) surface reaction for anion exchange between n-C₄H₉NH₃I vapor and CsPbBr3 nanoplates; and (ii) solid-state diffusion of I⁻ in the CsPbBr₃ nanoplates. (D) PL micrographs of individual nanoplates with varying thicknesses and at different reaction times. Scale bars: 5 μ m. (E-G) Snapshots of the MD simulation of halide interdiffusion. A chloride anion swaps with a vacancy in an equal-molar mixture, in the initial position (E), on top of the energy barrier (F), and in the final position (G). Color code: Cs in orange, Pb in black, Br in green, and Cl in blue. The sticks

represent the strong lead halide ionic bonds. (A), (B) and (E-G) are reproduced with permission from reference 65. (C) and (D) are reproduced with permission from reference 66.

4.1 Mechanisms of anion exchange and regulating the perovskite phase

Through temperature-dependent measurements of reaction rates, the activation energy values for both the Br⁻ to I⁻ and the Br⁻ to Cl⁻ exchanges were determined to be positive by Alivisatos *et al.*, suggesting the anion exchange is a kinetic process, with either surface reaction- or diffusion-limited mechanisms⁶⁶. The anions in perovskite structures are known to be highly mobile, so understanding the anion diffusion inside the solid-state lattice is essential to understanding of the anion exchange phenomena. Within this context, we studied joined CsPbCl₃-CsPbBr₃ NW heterojunctions to monitor the interdiffusion of Br⁻ and Cl⁻ across the two segments, by thermally-triggering the exchange and visualizing the dynamics *via* wide-field PL imaging (Figure 5A). Heating the NW at a constant temperature (100 °C) over different periods of time (Figure 5B), the PL peak evolution was tracked and both the Br-rich (green) and Cl-rich (blue) regions of the NW where spatially mapped. By analyzing the local Br/(Br+Cl) ratio along the NW as a function of time the halide interdiffusivities were determined to be 10^{-13} - 10^{-12} cm²/s at 75–125 °C. Plots of the temperature-dependent interdiffusion coefficients further revealed the activation energies for the halide diffusions to be 0.28 eV, by fitting with an Arrhenius equation.

By allowing vaporized n-Butylammonium iodide to react with a set of CsPbBr₃ nanoplates (20 to 350 nm-thick) simultaneously, Br- is systematically swapped for I- during our *in situ* PL probing and enables the anion exchange kinetics to be decoupled into two separate stages; a surface exchange reaction followed by subsurface ion diffusion (Figure 5C). The microscopic confocal PL imaging of the nanoplates at different reaction stages in Figure 5D shows a clear dependence of the anion exchange rates on both reaction time and plate thickness. Using a first-order description for the surface reaction and modelling the 1D vertical diffusion by Fick's second law, the iodide diffusion coefficient in the nanoplates was estimated to be on the order of 10^{-14} cm²/s at ~180 °C. Such diffusion-limited transformations ultimately led to the controlled formation of CsPbX₃ heterostructures, with distinctly separate Br-rich and I-rich regions⁶⁵.

Regarding the underlying origins of diffusion, our MD simulations suggest a halide vacancymediated mechanism (Figure 5E-G), given that the computed halide vacancy formation free energies are anticipated to be much smaller, leading to the high equilibrium vacancy concentrations that dominate the high interdiffusivities. As schematically illustrated in Figure 5E-G, the anions need to overcome the free energy barriers to diffuse by exchanging their positions with vacancies. It follows that intrinsic ion diffusion is facilitated by the soft lattice of halide perovskites, because of the low barriers for vacancy hopping revealed through MD simulations⁶⁴.

Anion exchange offers an appropriate route for accessing structures that are thermodynamically unstable or inaccessible via direct synthesis techniques. For example, the direct synthesis of CsPbI₃ NWs unavoidably results in a wide bandgap (~2.8 eV) yellow phase with poor optoelectronic performance⁶⁷. Alternatively, starting from CsPbBr₃ which forms a stable perovskite near RT, exchanging the Br for I resulted in a mixed alloy or fully exchanged CsPbI₃ materials, preserving the perovskite structure of the original host. Via exchange, a narrow, solar friendly bandgap as low as 1.76 eV can be realized. Further, the colloidal CsPbI₃ NWs resulting from anion exchange retained high PL quantum yields of around 81%, without any increase to defect densities, compared to the parent CsPbBr₃⁶⁸ systems.

The differing optical properties of the LT- and HT-phases expressed by all-inorganic CsPbI_xBr_{3-x} materials offer an interesting opportunity to reversibly switch between them, for environmentally driven thermochromic application. Using heat and moisture as triggers, we developed CsPbBr₂I thermochromic windows exhibiting varied optical transparency, depending on the environmental conditions (Figure 6A). At RT, the wide-bandgap (2.9eV), thermodynamically stable LT-phase is relatively transparent to visible light. Heating the window quickly transforms it to the HT-phase, changing its transparency from 81.7% to 35.4% and is a dark in appearance. Using this approach, both the transition temperature (105 to 320 °C) and band gap (1.7 to 2.3 eV for black phase), and thus transparency, can be tuned by varying the bromine to iodine ratio. Using a composition of CsPbIBr₂, for example, solar cell made from such an absorber exhibited PCEs above 7% and maintained more than 85% of this efficiency after 40 consecutive phase transition cycles.

Using direct laser write (DLW; cw 458 nm) as a local thermal trigger⁶⁹, we also explored the possibility of microprocessing functional HT-FAPbI₃ perovskite elements embedded into relatively insulating LT-phase single crystals. Due to the poor thermal conductively of perovskite in general⁷⁰, rapid DLW allowed for controlled restructuring of optically-active α -FAPbI₃ microstructures with lateral dimensions nearing the diffraction limit (<1 µm). Interestingly, unlike heated FaPbI₃ which lasts just a few days in the HT-phase, DLW transformations were lasting months under ambient conditions, likely due to the stabilizing heterointerface established between the LT- and HT-phases.

4.2 Fabricating functional heterojunctions



Figure 6. Control and design of functional nano-scale perovskite heterojunctions. (A) Photograph of LT-phase and HT-phase thin films, an interconversion between the two made reversible *via* heating and exposure to moisture. Reproduced with permission from reference 58. Copyright 2018 Springer Nature. (B) CL images of P-N heterojunction formed through a localized phase transition in a single CsSnI₃ NW (Scale bar: 5 µm.). (C) I–V characteristics of the P-N heterojunction shown in (B), measured using the four central electrodes. The Inset shows the relative energy band alignment of LT-CsSnI₃ and HT-CsSnI₃ under thermal equilibrium. Reproduced with permission from reference 72. Confocal PL mapping of (D) CsPbBr₃-CsPbCl₃, (E) CsPbI₃-CsPbBr₃ NWs and (F, top) CsPbI₃-CsPbBr₃-CsPbCl₃ NWs, and (F, bottom) different patterns on anion-exchanged CsPbBr₃ plates demonstrating the versatility of structures made using the current method. Blue emission: 410 to 450

nm. Green emission: 500 to 550 nm. Red emission: 580 to 640 nm. The scale bar for D, E, F, is equal to 3 µm. Reproduced with permission from reference 73.

The diverse range of photophysical properties arising from phase transitions and anion exchange have inspired the design of functional optoelectronic materials with sharp interfaces without using the conventional epitaxial growth methods. Utilizing a localized thermal-driven phase transition, we were able to control the transition completion in a single LT-CsSnI₃ NW and demonstrate p-n junction formation within a LT-CsSnI₃/HT-CsSnI₃ two-phase heterojunction structure⁷¹ (Figure 6B). As-synthesized LT-CsSnI₃ NWs show n-type conductivity, which is confirmed by a negative signals within Seebeck coefficient measurements. Upon thermal annealing, the Seebeck coefficient of HT-CsSnI₃ NWs becomes positive, confirming the electrical transition to p-type with the phase transition. To account for this, theoretical simulations suggest that a change from V_{I}^{+} to V_{Sn}^{2-} in the dominant defect-type results in a different majority carrier concentration between the two phases. CL microscopy with in-situ heating enables direct observation of the interface formation between them and clearly captures the directional interface propagation within a single NW (Figure 6B). As a result, the LT/HT-CsSnI₃ NW heterojunction exhibits current rectification, owing to the asymmetric p-n heterojunction properties (Figure 6C). Conventional p-n junctions are typically created by successive chemical doping processes and, thus, such phaseengineering of p-n junctions may enrich modern optical and electronic devices in halide perovskites. Further, the local nature of the heterojunction formed may act as fundamental building block toward high-density and large-scale applications.

By limiting anion exchange reactions to local regions on a single-crystalline nanomaterial using poly(methyl methacrylate) (PMMA) covers and electron beam lithography, we were able to demonstrate an effective way for directly obtaining halide perovskite semiconductor heterojunctions⁷². The two-segment or multiple heterojunctions between CsPbCl₃ to CsPbBr₃ or CsPbI₃ to CsPbBr₃ on single NWs displayed spatially resolved emissions ranging from red to blue with pixel sizes down to 500 nm (Figure 6D-F), confirming different local electronic structure. Such technological advances could be useful for miniaturised, high-density optoelectronic devices, like high resolution multicolour displays, large-scale integrated photonic devices or diode/transistor arrays.

5. CONCLUSIONS AND OUTLOOK

A paradigm exists within current halide perovskite research that "structure defines properties", however the question "what is the structure?" often remains open. Although it is a heavy task to fully understand the nature of phase transitions and anion exchange within halide perovskites, unlocking technologically relevant insights are likely to lead to important advances for the field. As such, this Account aimed to explore the origins of polymorphism and anion exchange phenomena within metal halide perovskites.

When the soft perovskite lattice diverges from normal equilibrium conditions, i.e., what one might consider the bulk properties, the phase energetics are shown to be inherently altered and may in fact be tailored toward more stable room temperature perovskite structures. On the other hand, environmental triggers, like moisture exposure, can act to destabilize its dynamic surface and catalyses a non-perovskite phase transition pathway which is mediated by an amorphous interfacial boundary. Ultimately, researchers need to isolate which aspects of (post)synthetic processing are key enablers, and inhibitors, for developing device-ready materials. For example, while the creation of nanocrystals and targeted surface functionalization can improve long-term phase stability (enabled by anchoring the Pb-X₆ octahedra⁷³) and suppress halide migration/segregation⁷⁴, they can also impede charge carrier transport⁷⁵ and the overall modified "big picture" must then be considered wisely.

As emphasised by several examples throughout this Account, the post-synthetic treatment of halide perovskite nano- and micro-crystals using local anion exchange and thermal-phase changes makes for a scientifically interesting toolbox. For instance, due to the intrinsic dependence of their optical properties on structure and composition, *in situ* luminescence microscopy has done well to not only visualize the transformation kinetics, but also quantify them. In the end, *in situ* characterisation methods have proven invaluable and have directly led to more comprehensive depictions of the dynamic halide perovskite crystal structure. For a versatile range of optoelectronic functions, flexible expressions of both phase and composition, down to the nanoscale, has inspired several lines of exciting applied research. Most notably, the realization of thermochromic windows, P-N junctions and high-density heterojunction arrays. Recently, the potential for highly stable and

tunable lateral epitaxial heterostructures was advanced by adding rigid π -conjugated organic ligands to inhibit in-plane ion diffusion in two-dimensional halide perovskites⁷⁶. Such discoveries will hopefully help clear a path beyond perovskite/perovskite heterostructures, and toward the fabrication of more complex functional epitaxial structures. For instance, PbS quantum dots coherently embedded into a metal halide perovskite matrix have now been realised⁷⁷, permitting control over important photophysical features, like charge transfer efficiencies⁷⁸ and carrier diffusion⁷⁹. We anticipate that shining a light on these topics will help broaden the knowledge base from which the field can explore and build interesting technologies moving forward.

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